NSN 5961-01-175-8066



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-175-8066 **Inclosure Material:** Metal **Overall Length:** 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-52 **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 drain to gate voltage and -25.0 gate to source voltage **Current Rating Per Characteristic:** 20.00 milliamperes gate current **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation **Precious Material And Location:** Lead surfaces gold **Precious Material: Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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